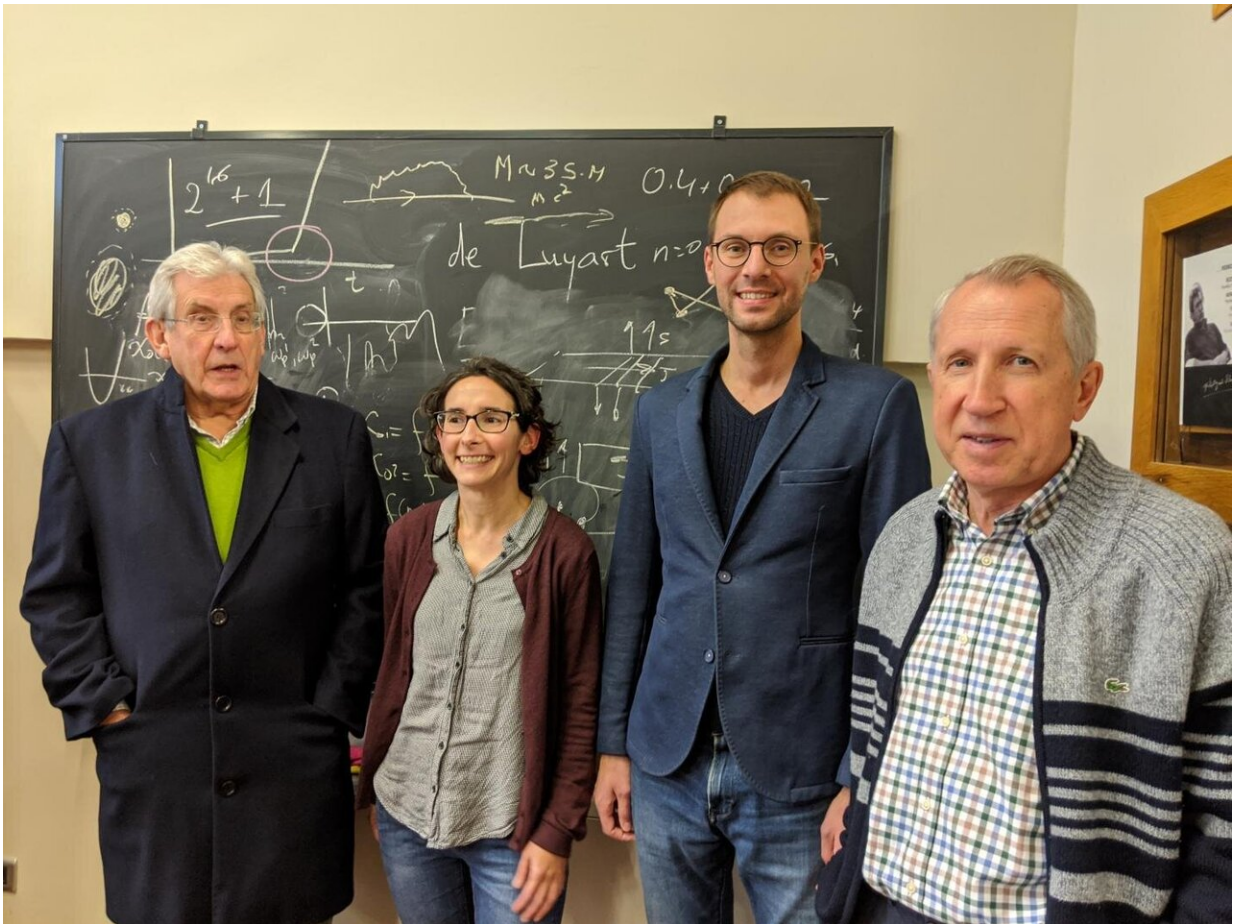


# First intrinsic magnetic topological insulator discovered

December 19 2019

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The researchers Credit: UPV/EHU

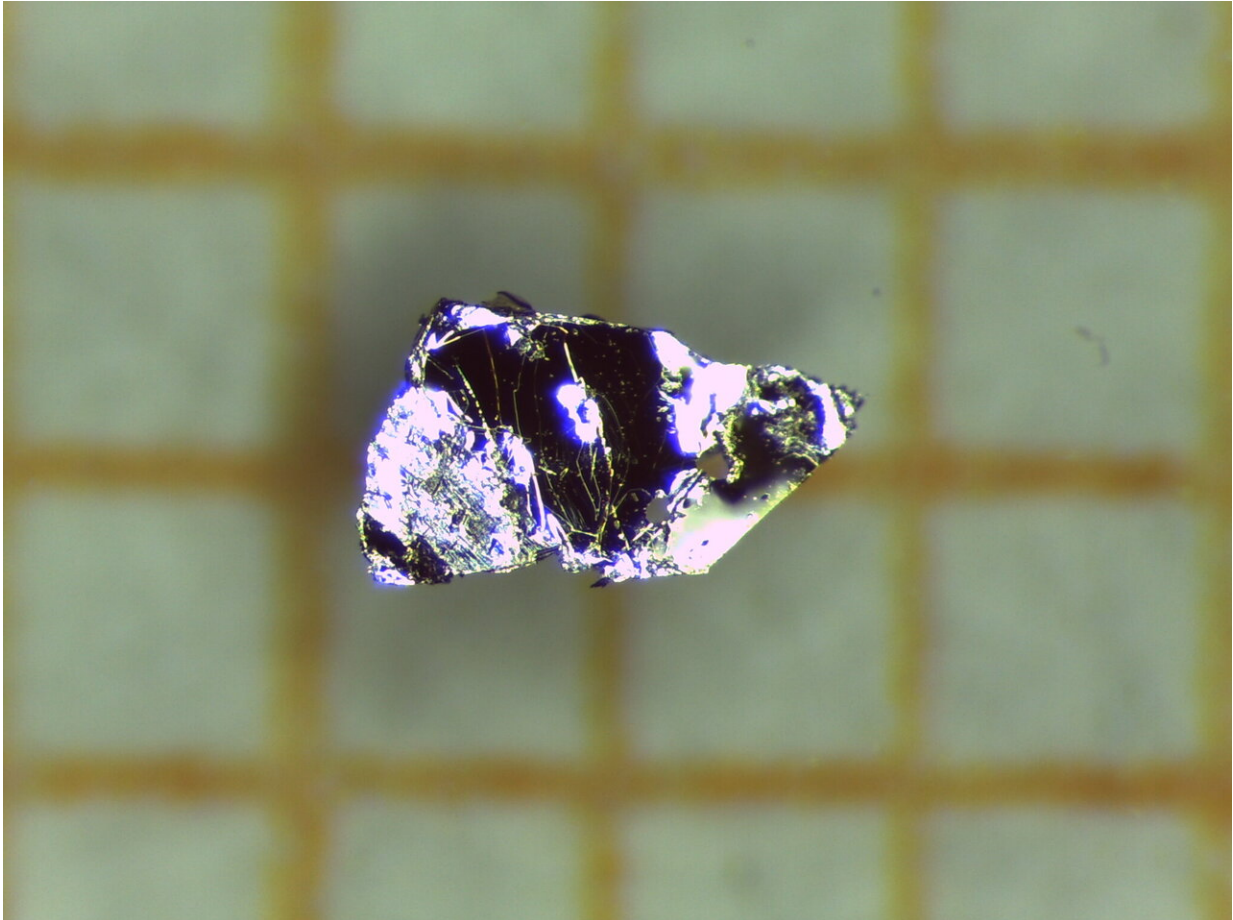
The so-called topological insulators are those materials that are insulators

in bulk, i.e., those that do not allow electric currents in their volume, but that are conductors on their surfaces. Unlike the usual conductors, that is, metals, the electric current circulating in a topological insulator does not suffer any loss of energy. This property opens great possibilities for application in electronics, since it would enable the fabrication of more efficient, faster and low-energy consumption devices. This is an objective as desirable as it is necessary in the current scenario of rapid advance of energy demand worldwide, which threatens our environment. For that very reason, the discovery of topological insulators about a decade ago caused a global research boom in the fields of nanotechnology and condensed matter physics.

With technological applications in mind, for example in information technologies, one of the challenges during these years of intense research has been the creation of a magnetic [topological insulator](#). So far, magnetic topological insulators had only been created by the so-called extrinsic route, which consists of doping nonmagnetic topological insulators with magnetic atoms. However, thanks to the efforts of a group of researchers from the Materials Physics Center (CFM, CSIC-UPV/EHU joint centre), Donostia International Physics Center (DIPC) and the University of the Basque Country (UPV/EHU), it is now possible to grow an intrinsic magnetic topological [insulator](#), that is, one that has magnetic properties by its own very nature.

The team that includes DIPC researchers Mikhail Otkov (CFM Ikerbasque Research Fellow), Evgueni Chulkov (UPV/EHU, Euskadi Research Prize 2019), María Blanco Rey (UPV/EHU) and Pedro M. Echenique (UPV/EHU, DIPC President), has predicted theoretically the first intrinsic magnetic topological insulator, with chemical formula  $\text{MnBi}_2\text{Te}_4$ . The key to the success of this prediction has been the vast amount of experience that this group of scientists has in the fields of topological insulators, magnetism and material science in general. The Ikerbasque fellow and leader of this research, Mikhail Otkov, states

that "previous work from different approaches led us to the conclusion that the intrinsic route was the only feasible one nowadays. Then, we directed our efforts to find an intrinsic magnetic topological insulator based on our prior experience. Thanks to that, we knew what crystalline structure and atomic composition such a material should have."



MnBi<sub>2</sub>Te<sub>4</sub> single crystal. Credit: (c) Anna Isaeva

Donostia (Basque Country, Spain) is not only the place where the theoretical prediction of this first magnetic topological insulator has

been carried out, but it has also been the base camp from where its experimental confirmation has been coordinated. This work has involved experts in different areas, from leading research centres in Russia, Azerbaijan, Germany, Austria, Japan, Italy and the U.S.. The results of this study are being published this week in the prestigious journal *Nature*. Otrokov has explained that for experimental confirmation, the first step was the synthesis of the compound crystals by the chemical synthesis experts. Once synthesized, the samples were subject to a multitude of characterization experiments—structural, magnetic, electronic, of transport, of atomic composition, etc—until the predicted characteristics were observed and verified.

The results of the study, which had already been disseminated through an open-access server and lectures delivered by the authors at international conferences, have been well received by the international scientific community. Currently,  $\text{MnBi}_2\text{Te}_4$  and other materials based on it are studied in several research centers, those of the U.S. and China showing the most intense activity.

" $\text{MnBi}_2\text{Te}_4$ , besides being an intrinsic magnetic topological insulator, has turned out to be [antiferromagnetic](#), just as we had calculated," Blanco tells us. Antiferromagnetism consists of a magnetic order at an atomic scale, such that the material lacks net magnetization. As a result, these materials are much more robust against perturbations by magnets.

This crystal composed of Manganese (Mn), Bismuth (Bi) and Tellurium (Te) has a great potential both at a fundamental and a technological level. It is extremely rich in exotic properties, for example, such as the various Hall effects, including the quantum ones, some of which are used in the calibration of physical constants for its exceptional precision. In addition,  $\text{MnBi}_2\text{Te}_4$  can be used to create the so-called Majorana fermion. This is a kind of particle, a quasiparticle to be accurate, that has been considered the cornerstone of quantum computing.



Likewise,  $\text{MnBi}_2\text{Te}_4$  is the first intrinsic material for which an electromagnetic response very similar to that of an axion is predicted. An axion is a hypothetical particle postulated in the framework of quantum chromodynamics, and it is a good candidate to solve the problem of dark matter. That is why there are a lot of experiments aimed precisely at detecting signals of axion-type behaviour in the family of this compound.

Regarding the practical applications, several devices based on magnetic topological insulators have already been patented. For instance,  $\text{MnBi}_2\text{Te}_4$  could be used in chiral interconnect devices, which promise superior performance to the ordinary copper connections currently used in commercially available integrated circuits. Some other applications include optical modulators, magnetic field sensors and memory elements.

The researchers working in Donostia, together with their network of international collaborators, expect to be able to observe in  $\text{MnBi}_2\text{Te}_4$  some of the exotic phenomena mentioned above, and discover new intrinsic magnetic topological insulators with even superior properties than those of  $\text{MnBi}_2\text{Te}_4$ .

**More information:** M. M. Otrokov et al, Prediction and observation of an antiferromagnetic topological insulator, *Nature* (2019). [DOI: 10.1038/s41586-019-1840-9](https://doi.org/10.1038/s41586-019-1840-9)

Provided by University of the Basque Country

Citation: First intrinsic magnetic topological insulator discovered (2019, December 19) retrieved 22 July 2024 from <https://phys.org/news/2019-12-intrinsic-magnetic-topological-insulator.html>

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